

FACILE PREPARATION AND CHARACTERIZATION OF LAYERED MoS₂ NANOSHEETS

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Free-standing two-dimensional (2D) nanomaterials, such as graphene, boron nitride (BN), and molybdenum disulfide (MoS₂) with atomic thickness, have attracted extensive attentions because of their unique properties. In recent years, the study of atomically thick 2D nanosheets has mainly focused on the layered materials with weak van der Waals forces between the layers. Here, MoS₂ nanosheets have been successfully prepared by a facile, efficient, and scalable method using combined low-energy ball milling and sonication. The obtained products were characterized by X-ray powder diffraction (XRD), transmission electron microscopy (TEM), atomic force microscopy (AFM) and Raman spectroscopy. The influences of milling speed on the exfoliation of MoS₂ nanosheets were carefully investigated.

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1. Introduction

Transition metal dichalcogenides MX₂ (M = Mo, W, Nb and Ta, X = S, Se), which possess a layered structure, striking properties and promising applications, have attracted great attentions [1]. MoS₂ is one of the layered transition metal dichalcogenides. Monolayer MoS₂, compared to its bulk form, is a semiconductor with a direct band gap of 1.8 eV, and has a high fluorescence yield [2]. These unique properties make them promising candidates for wide applications in catalysis [3], energy storage [4], electronics [5,6], solid lubrication [7,8], hydrogen storage [9], and Li batteries [10]. The layered MoS₂ is constructed by unit S-Mo-S atoms, which has a covalent bond between metal and chalcogen, and weak van der Waals forces among the layers. Therefore, single or few-layer nanosheets of these materials can be obtained by using adhesive tapes for micromechanical cleavage, which was applied as the first method for mechanical fragmentation of layered materials into individual 2D nanosheets and has been used to prepare MoS₂ nanosheets [11]. Although this method provides high quality 2D nanosheets, the extremely low yield is a critical problem. Therefore, much effort has been devoted to prepare MoS₂ nanosheets with high yields and unique properties.

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Recently, Zeng et al. have demonstrated a controllable lithium intercalation process via incorporation of layered bulk materials, such as MoS₂, WS₂, TiS₂, TaS₂, ZrS₂, and graphite, as the cathode in an electrochemical set-up [12]. However, the complicated electrochemical process is time consuming, extremely sensitive to the environment and incompatible with most solvents. Hence, it is desirable to develop an effective and facile approach for the preparation of MoS₂ nanosheets on a large scale in order to broaden their practical applications.

Herein, we demonstrate a simple and effective method to fabricate high-yield, single-layer 2D nanomaterials using a combined low-energy ball milling and sonication method. Also, the influences of the milling speed on the exfoliation of MoS₂ nanosheets were studied. The approach produced high yield MoS₂ nanosheets, which opens up possibilities for potential scalable applications.

2. Experimental details

2.1 Preparation of MoS₂ nanosheets samples

For preparing 2D MoS₂ nanosheets, 3.0 g MoS₂ raw powders and 200 ml 0.05 wt.% SDBS–water were loaded in a sealed polyethylene bottle with 90 g agate balls and then ball milled. The rotation speed of the planetary mill was set at 200 rpm. Some of the milled samples were taken out after milling for 12 h, followed by centrifugation at 5000 rpm for 20 minutes. After that, an additional 3 h of sonication of MoS₂ supernatants was applied.

2.2 Characterization methods

The X-ray diffraction (XRD) patterns were obtained using a D8 advance (Bruker-AXS) diffractometer with the 2 θ range from 10 to 80°. The morphologies and structures of the samples were characterized by transmission electron microscopy (TEM) with a Japan JEM-100CX II transmission electron microscope and Atomic Force Microscope (AFM, MicroNano D3000). SERS spectra were investigated by Raman laser spectrometer (DXR) at the excitation line of 632.8 nm.

3. Results and discussion

3.1 Structure and morphology characterization

MoS₂ nanosheets were obtained by a combined low-energy ball milling and sonication method. The crystalline structure of initial bulk MoS₂ powders and the obtained MoS₂ nanosheets were confirmed by XRD, as shown in Fig. 1a. In the XRD patterns, the (002) reflection of the MoS₂ nanosheets is significantly weaker than that of the bulk MoS₂ powders. The weak peak can be caused by both a reduction in crystallite size and an increase in lattice strain [13]. Fig. 1b displays the Raman spectra of initial bulk MoS₂ powders and MoS₂ nanosheets excited by 632.8 nm line. The Raman spectra of both the initial bulk powders and the thin nanosheets of MoS₂ show two peaks at 379 and 405 cm⁻¹. The intense Raman peaks of the MoS₂ nanosheets offer strong evidence that the MoS₂ nanosheets are successfully prepared and of high quality.

The structure and morphology of MoS₂ nanosheets were studied by TEM (Fig. 1c and d). As shown in Fig. 1c, the MoS₂ nanosheets were transparent to the electron beam due to their ultrathin thickness. The inset in Fig. 1d shows the SAED pattern of MoS₂ nanosheets. The pattern reveals a typical six-fold symmetry of MoS₂ nanosheets with high crystallinity, few defects, and an intrinsic structure. A typical photograph of MoS₂ suspension is shown in Fig. 1e. In our work, we also found that the dispersion of MoS₂ nanosheets is stable over periods of hundreds of hours.

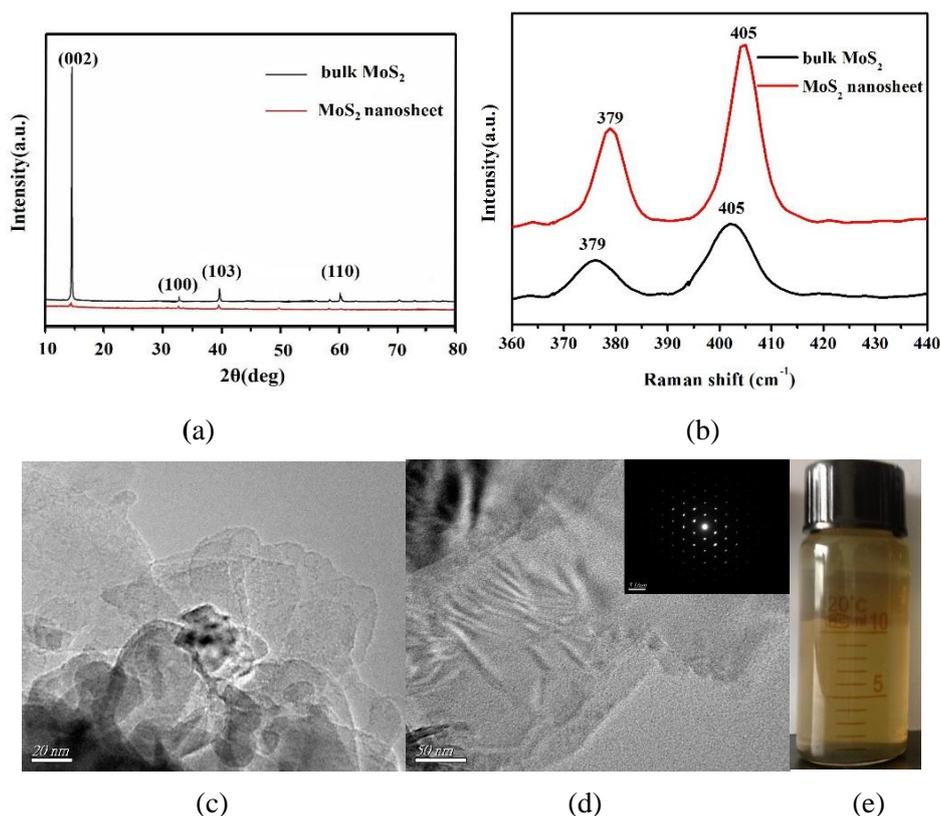


Fig. 1 XRD(a), Raman(b), TEM(c,d) and dispersion images(e) of the as-prepared MoS₂ nanosheets

3.2 Influences of the milling speed

In order to study the influences of the milling speed on the exfoliation of MoS₂ nanosheets, a series of experiments have been performed. The milling speed was set at 100 rpm, 200 rpm and 250 rpm, respectively. Fig. 2 shows TEM and AFM images of the exfoliated MoS₂ nanosheets. It can be seen from the TEM and AFM images (Fig. 2a) that the nanosheets corresponding to the products of the milling speed at 100 rpm are poorly exfoliated and stacked together. An enlargement area was characterized using AFM and the red line was marked. The height of the selected two points on the red line was 8.4 nm. The selected nanosheet possesses about 14 layers from the previous theoretical and experimental results that the monolayer thickness is 0.6 nm for S-Mo-S structures [14]. MoS₂ nanosheets were sharply thinning at the milling speed of 200 rpm and the thickness reached to 2.4 nm, which indicated that the number of layers was reduced to four (Fig. 2b). The milling speed was further increased to 250 rpm, and the height of the selected two points of AFM images (Fig. 2c) was measured to be 1.8 nm. It can be seen that nanosheets thickness decreases with the increasing milling speed. The thickness of the nanosheets varies little

when the milling speed reaches to 250 rpm. What's more, from the TEM images (Fig. 2b and 2c), it can be seen that we have already successfully prepared monolayer and few-layered MoS₂ nanosheets though the monolayer MoS₂ nanosheet didn't appear yet in the selected area of AFM images.

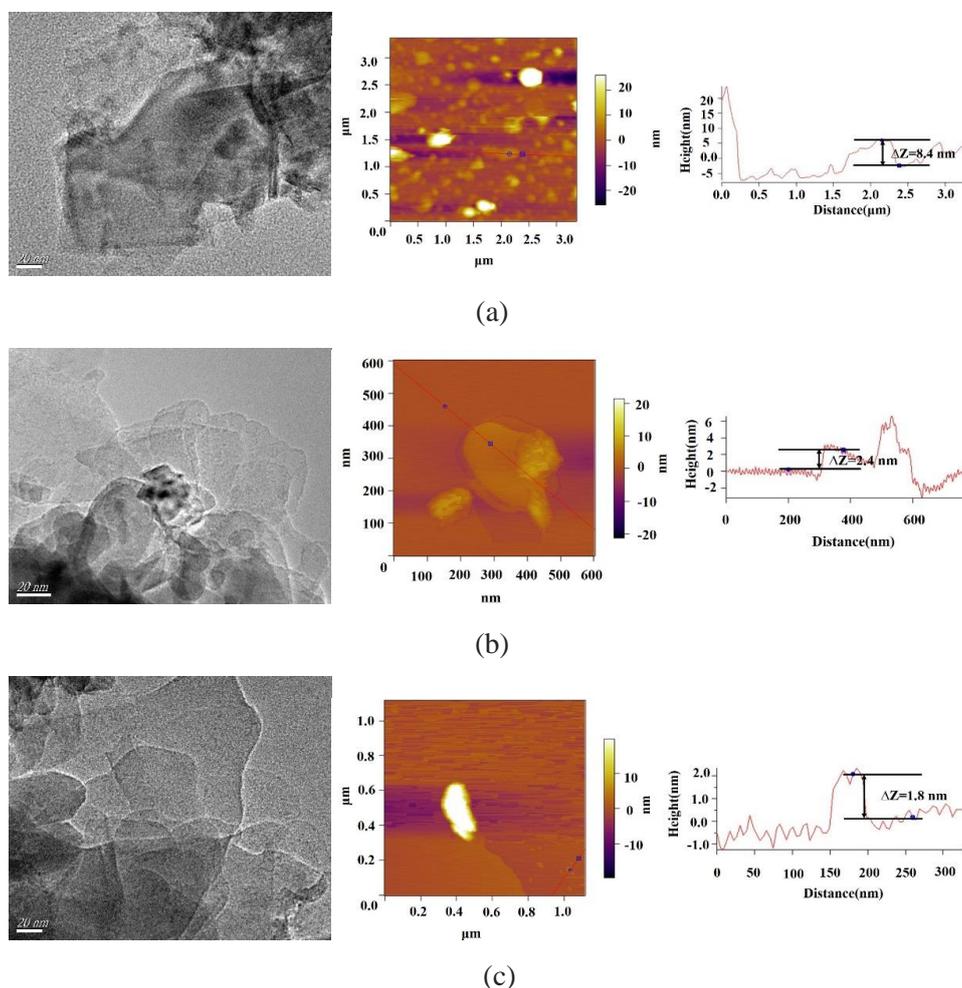


Fig. 2. TEM and AFM images of MoS₂ nanosheets obtained at different milling speed: a) 100 rpm, b) 200 rpm and c) 250 rpm

SERS spectra of MoS₂ nanosheets prepared at different milling speed are shown in Fig. 3. It displays the Raman spectra of MoS₂ nanosheets excited by 632.8 nm line in air ambient environment. As shown in Fig.3, the peaks of the MoS₂ nanosheets is nearly consisten. The characteristic peaks of the MoS₂ nanosheets obtained at the milling speed of 200 rpm is relatively strong, which may result from its relatively uniform layers and size.

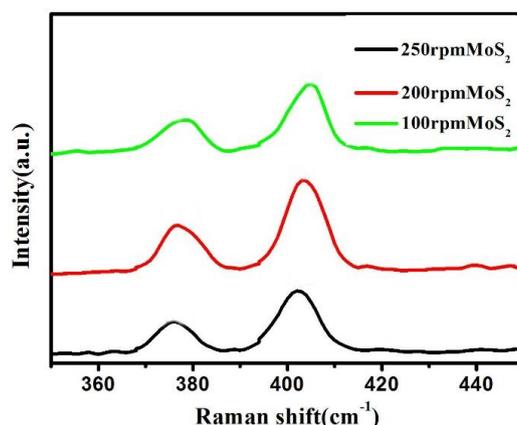


Fig. 3. Raman characterization of MoS₂ nanosheets obtained at different milling speed:
(a) 100 rpm, b) 200 rpm and c) 250 rpm

4. Conclusions

In summary, 2D MoS₂ nanosheets have been obtained successfully via a combined low-energy ball milling and sonication method. The influences of the milling speed on layers of the MoS₂ nanosheets were discussed. When the milling speed is 250 rpm, the MoS₂ nanosheets have already been deeply exploited. This efficient and simple method can be applied as a general method for the production of 2D nanosheets especially transition metal dichalcogenides. This proposed approach will have great potential prospects for development of large scale 2D materials-based devices.

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